



# IA02001000P60; 200-1000 MHz 1000W AMPLIFIER

## FEATURES

- Solid-state Class AB
- GaN on SiC Transistors

## GENERAL DESCRIPTION

IA02001000P60 is a 1000W rack-mount Power Amplifier device designed with Solid State technology. This device has a wide band operating frequency starting from 0.2 GHz to 1.0 GHz.



## ELECTRICAL SPECIFICATIONS

Frequency:	200-1000 MHz
Output Power:	1000 W min.
Nominal Gain:	60 dB
Overdrive Input Power	+10 dBm
Input VSWR	2:1 typ.
Load VSWR	∞:1 (Fully mismatch tolerant)
Harmonics (2nd / 3rd)	15 dBc / 20 dBc
Spurious	55 dBc typ.
Line Power	7000 VA

## MECHANICAL & ENVIROMENTAL SPECIFICATIONS

RF Input:	N - FEMALE
RF Output:	N - FEMALE
Operating Ambient Temperature	-20 to 55 °C
Storage Temperature	-30 to 85 °C
Relative Humidity	Up to 95%
Operating Altitude	Up to 3000 meters above sea level
Cooling	Internal Cooler
Dimensions	19" (W) x 13U (H) x 660 mm (L)

## BUILT-IN FUNCTIONS

Power Monitoring  
LCD Display  
Ethernet

## OPTIONS

- OPT-1:** Harmonic Filter \*
- OPT-2:** RF Switching Unit \*
- OPT-3:** RS-485, CAN BUS, RS-232, GPIB

\* Output power may be degraded with those options